

Identification of elastic properties of a Si-based joint using deformation fields determined by using Digital Image Correlation -Application to the mechanical behaviour of CMC brazed composites-

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I. Scope

- Specific adhesives are required for ceramics and CMCs: BraSiC [1] (Si-based braze) for SiC-based materials, e.g., monolithic SiC and 2D SiC/SiC composites.
- Data on joint materials are required for design purposes and failure predictions [2].
- Determination of joint properties is generally difficult because of the size and volume of available samples (less than 100 µm thick).
- This study aims at extracting elastic properties (E_{joint} and v_{joint}) from strain fields determined using Digital Image Correlation [3] with a view to analyzing brazed composites structures.

2. Experimental procedure & materials



4. Extraction of elastic properties

- Equations of strains
- → Transverse displacements in the BraSiC joint are dictated by Poisson effect in the SiC substrate

$$\begin{aligned} -\text{Tension (T):} & \begin{cases} U_{y,\text{joint}} = U_{y,\text{SiC}} \\ U_{z,\text{joint}} = U_{z,\text{SiC}} \end{cases} \Rightarrow \epsilon_{xx,\text{joint}}^{(T)} = \frac{F}{S} \left[\frac{1}{E_{\text{joint}}} - \frac{2\nu_{\text{joint}}}{1 - \nu_{\text{joint}}} \left(\frac{\nu_{\text{joint}}}{E_{\text{joint}}} - \frac{\nu_{\text{SiC}}}{E_{\text{SiC}}} \right) \right] \\ -\text{Off-axis compression (C45):} \\ U_{z,\text{joint}} = U_{z,\text{SiC}} \Rightarrow \begin{cases} \epsilon_{x'x',\text{joint}}^{(C45)} + \frac{\nu_{\text{joint}}}{1 - \nu_{\text{joint}}} \epsilon_{y'y',\text{joint}}^{(C45)} = \frac{F}{2S} \left[\frac{1}{E_{\text{joint}}} - \frac{2\nu_{\text{joint}}}{1 - \nu_{\text{joint}}} \left(\frac{\nu_{\text{joint}}}{E_{\text{joint}}} - \frac{\nu_{\text{SiC}}}{E_{\text{SiC}}} \right) \right] \\ \epsilon_{x'x',\text{joint}}^{(C45)} = \frac{1 + \nu_{\text{joint}}}{E_{\text{joint}}} \frac{F}{2S} \\ -\text{Cost function } (J_{3D}): \\ \mathcal{J}_{3D} (E_{\text{joint}}, \nu_{\text{joint}}) = \sum_{F} \left[\epsilon_{xx,\text{exp.}}^{(T)} (F) - \epsilon_{xx}^{(T)} (F) \right]^{2} + \sum_{F} \left[\left(\epsilon_{x'x',\text{exp.}}^{(C45)} (F) + \frac{\nu_{\text{joint}}}{1 - \nu_{\text{joint}}} \epsilon_{y'y',\text{exp.}}^{(C45)} (F) \right) \right] \end{cases}$$



- Measurements at high magnification
- → An error is calculated by comparing DIC displacement results of an image numerically shifted by a constant vector and the prescribed displacement.



- Cost function (J_{4By}) : $\mathcal{J}_{4By}(E_{\text{joint}},\nu_{\text{joint}}) = \sum_{F} \sum_{\{x,y\}} \left[\mathbf{U}_{y,\text{exp.}}(x,y,F) - \mathbf{U}_{y,\text{FEM}}\left(x,y,F,\frac{E_{\text{joint}}}{E_{\text{SiC}}},\nu_{\text{joint}},\nu_{\text{SiC}}\right) \right]^2$



6. An example of application to a brazed 2D SiC,/SiC







- (a) Average error for different images (magnification: 1 pixel = $0.33 \mu m$)
- (b) Average error vs. image coding (magnification: 1 pixel = $0.33 \mu m$)
- (c) Comparison of optical and strain gauge measurements: rms error = 9×10^{-6} (SiC beam tested in uniaxial tension)

References

[1] F. Moret et al., Brazing of SiC based materials using the BraSiC process chemical and thermal application, Int. Conf. on joining of advanced materials, 1998. [2] M. Singh et al., Design, fabrication, and testing of ceramic joints for high temperature SiC/SiC composites, J. of Eng. for Gas Turbines and Power, 123, pp. 288–292, 2001. [3] F. Hild et al., Multiscale displacement field measurements of compressed mineralwool samples by digital image correlation, Appl. Optics, **41**(2), pp. 6815–6827, 2002. [4] S. Pompidou et al., Model of deviation of cracks at interfaces/interphases based on the Cook and Gordon's mechanism, HTCMC-5, In press, 2004.



(a) in situ brazed 2D SiC/SiC visualization

Elastic properties

	Young's modulus, <i>E</i> (GPa)	Failure stress, σ ^R (MPa)
SiC	420	-
BraSiC	153	80*

(b) SEM micrograph of BraSiC joint / CMC substrate interface $(x = x_0)$

(c) crack arrest capability condition for debonding [4]

$$\frac{E_{\rm BraSiC}}{E_{\rm SiC}} = 0.36 \Rightarrow \frac{\sigma_{\rm BraSiC/SiC}^R}{\sigma_{\rm BraSiC}^R} = 0.15$$

current situation: $\sigma_{BraSiC/SiC}^R > 12 \text{ MPa}$

debonding: $\sigma_{\text{BraSiC/SiC}}^R < 12 \text{ MPa}$

* determined in a companion study

7. Summary

- Potential of the DIC technique for strain analysis has been demonstrated in extreme conditions: high magnification (1 pixel = 0.33 μ m), low strain level (<10⁻⁴), small amount of material.
- Comparison of strain fields determined using DIC method and theory or finite element computations allow for in situ identification of elastic properties of the BraSiC material.
- Joint properties can be used to analyze and understand the mechanical behaviour and failure of CMC composite brazed structures.